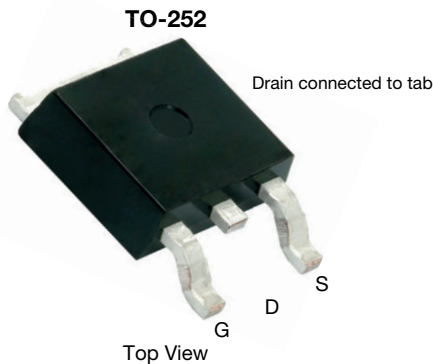




**THE DATASHEET OF
SQD40031EL_GE3**



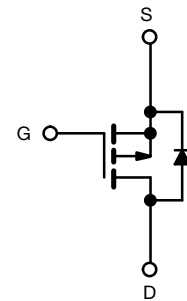
Automotive P-Channel 30 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Material categorization:
for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


P-Channel MOSFET

PRODUCT SUMMARY

V _{DS} (V)	-30
R _{DS(on)} (Ω) at V _{GS} = -10 V	0.00320
R _{DS(on)} (Ω) at V _{GS} = -4.5 V	0.00520
I _D (A)	-100
Configuration	Single
Package	TO-252

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V _{DS}	-30	V
Gate-source voltage	V _{GS}	± 20	
Continuous drain current	I _D	T _C = 25 °C ^a	-100
		T _C = 125 °C	-94
Continuous source current (diode conduction) ^a	I _S	-100	A
Pulsed drain current ^b	I _{DM}	-300	
Single pulse avalanche current	I _{AS}	-41	
Single pulse avalanche energy	E _{AS}	84	mJ
Maximum power dissipation ^b	P _D	T _C = 25 °C	136
		T _C = 125 °C	45
Operating junction and storage temperature range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R _{thJA}	50	°C/W
Junction-to-case (drain)	R _{thJC}	1.1	

Notes

- Package limited
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)



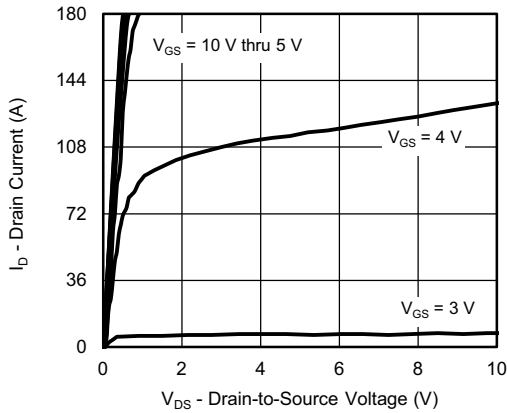
SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V, V _{DS} = -30 V	-	-	-1	μA
		V _{GS} = 0 V, V _{DS} = -30 V, T _J = 125 °C	-	-	-50	
		V _{GS} = 0 V, V _{DS} = -30 V, T _J = 175 °C	-	-	-250	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V, V _{DS} ≥ -5 V	-50	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V, I _D = -30 A	-	0.00263	0.00320	Ω
		V _{GS} = -10 V, I _D = -30 A, T _J = 125 °C	-	-	0.00438	
		V _{GS} = -10 V, I _D = -30 A, T _J = 175 °C	-	-	0.00502	
		V _{GS} = -4.5 V, I _D = -25 A	-	0.00425	0.00520	
Forward transconductance ^b	g _{fs}	V _{DS} = -15 V, I _D = 30 A	-	98	-	S
Dynamic ^b						
Input capacitance	C _{ISS}	V _{GS} = 0 V, V _{DS} = -25 V, f = 1 MHz	-	11 085	15 000	pF
Output capacitance	C _{OSS}		-	1342	1900	
Reverse transfer capacitance	C _{RSS}		-	1181	1600	
Total Gate Charge ^c	Q _g	V _{GS} = -10 V, V _{DS} = -15 V, I _D = -100 A	-	186	280	nC
Gate-source charge ^c	Q _{gs}		-	28	-	
Gate-drain charge ^c	Q _{gd}		-	28	-	
Gate resistance	R _g	f = 1 MHz	1.7	3.5	5.3	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = -15 V, R _L = 0.2 Ω I _D ≅ -100 A, V _{GEN} = -10 V, R _g = 1 Ω	-	16	25	ns
Rise time ^c	t _r		-	204	310	
Turn-off delay time ^c	t _{d(off)}		-	126	190	
Fall time ^c	t _f		-	72	110	
Source-Drain Diode Ratings and Characteristics ^b						
Pulsed current ^a	I _{SM}		-	-	-300	A
Forward voltage	V _{SD}	I _F = -30 A, V _{GS} = 0 V	-	-0.8	-1.5	V
Body diode reverse recovery time	t _{rr}	I _F = -40 A, di/dt = 100 A/μs	-	66	135	ns
Body diode reverse recovery charge	Q _{rr}		-	100	200	nC
Reverse recovery fall time	t _a		-	31	-	ns
Reverse recovery rise time	t _b		-	35	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.4	-

Notes

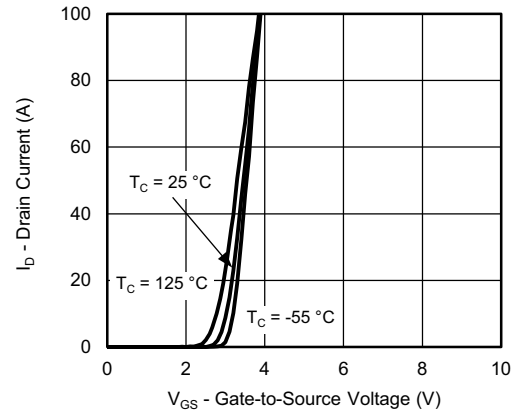
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

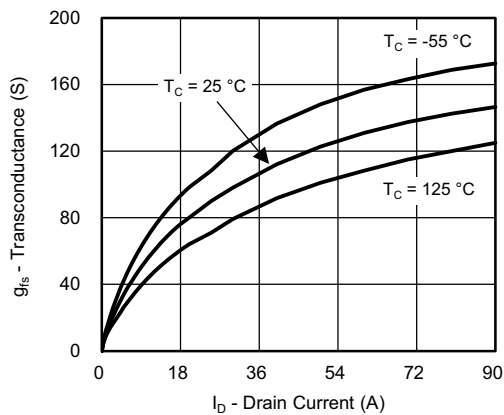
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



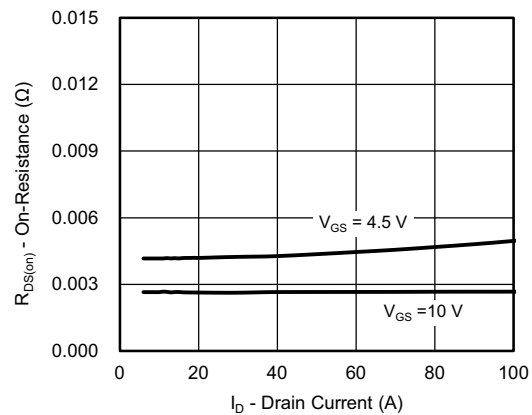
Output Characteristics



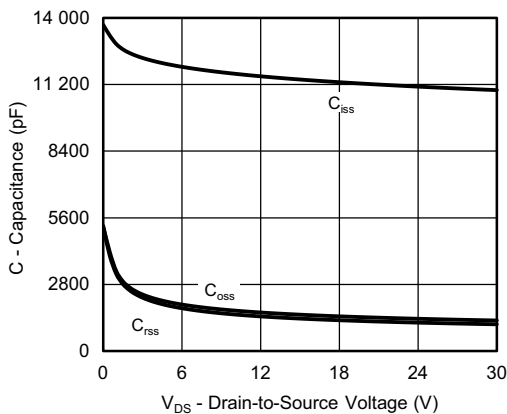
Transfer Characteristics



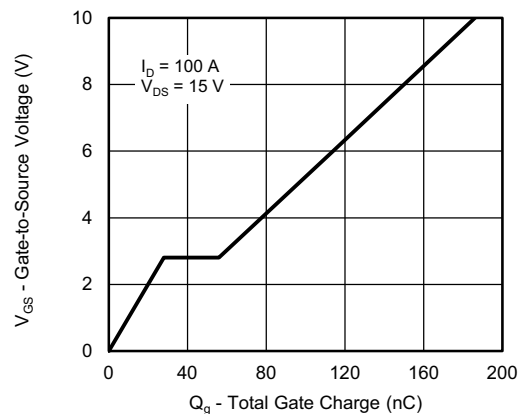
Transconductance



On-Resistance vs. Drain Current

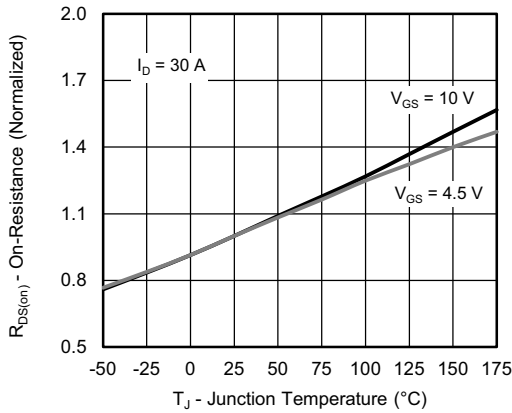


Capacitance

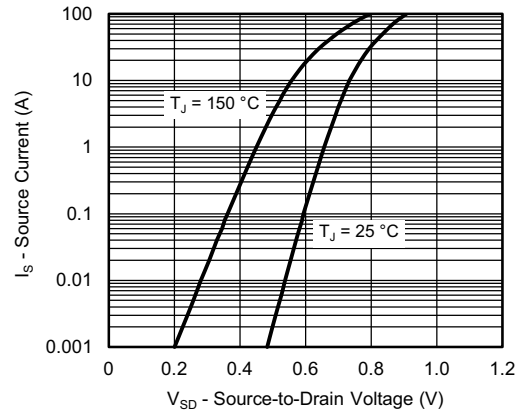


Gate Charge

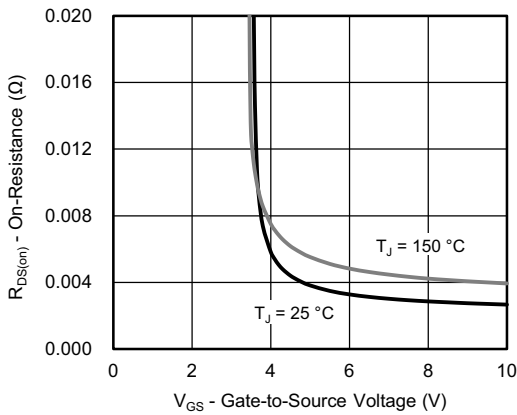
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



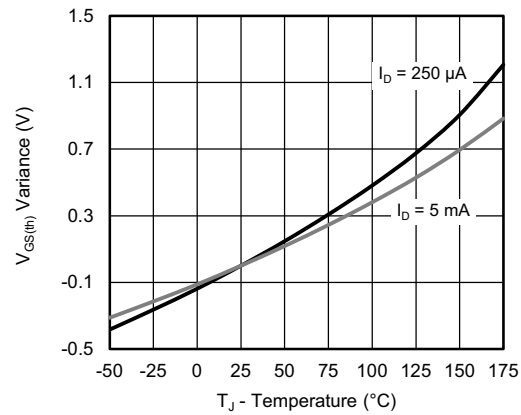
On-Resistance vs. Junction Temperature



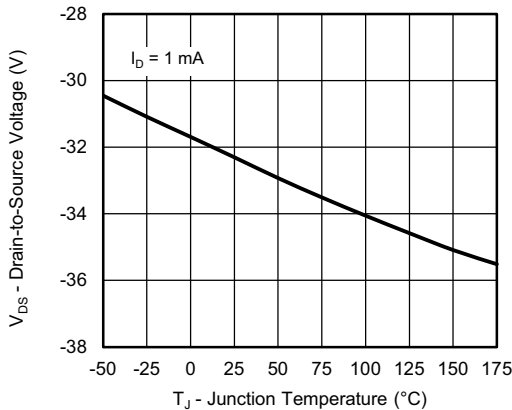
Source Drain Diode Forward Voltage



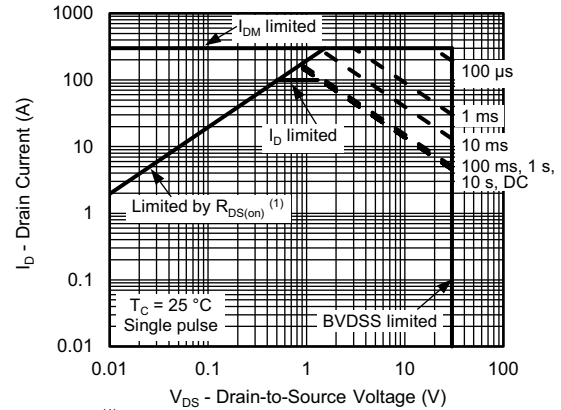
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



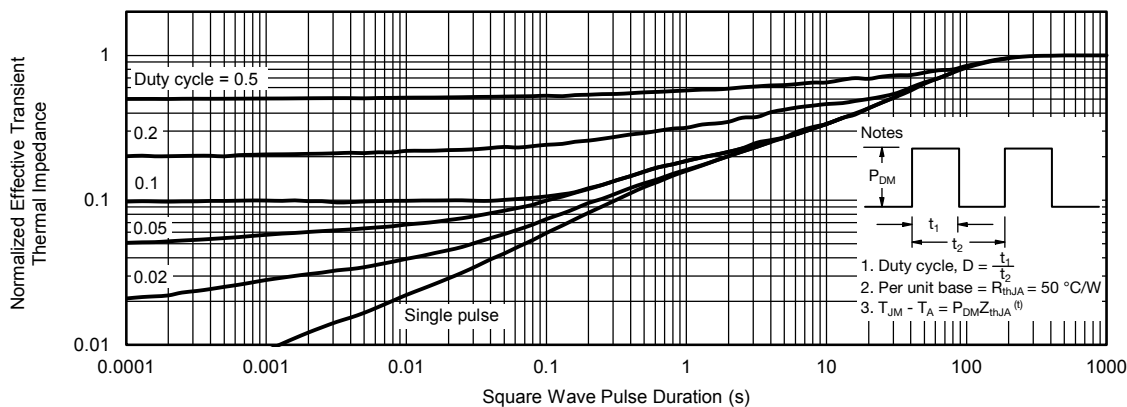
Drain Source Breakdown vs. Junction Temperature



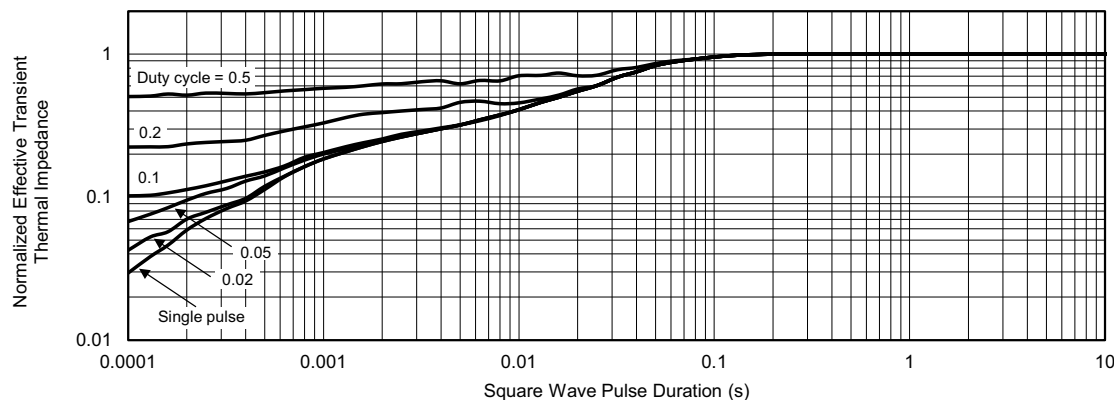
⁽¹⁾ $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to- Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Case ($25\text{ }^\circ\text{C}$)
- are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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TO-252AA Case Outline

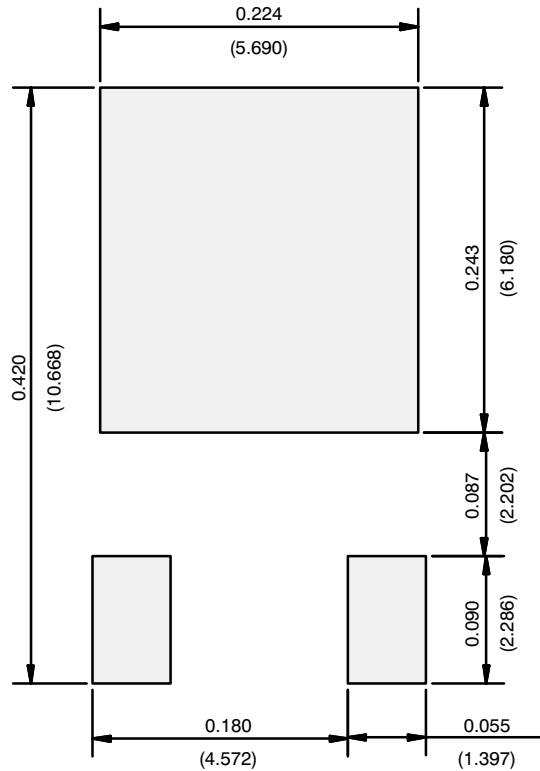


DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
C	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
H	9.40	10.41	0.370	0.410
e	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019				

Note

- Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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